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BZT585B2V4T - BZT585B43T

SURFACE MOUNT PRECISION ZENER DIODE

Features

- ±2.0% Tolerance on Breakdown Voltage
- Small, Low Profile Surface Mount Package
- Flat Lead Package Design for Low Profile and High Power Dissipation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOD523
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Band
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe.
 Solderable per MIL-STD-202, Method 208 63
- Weight: 0.001 grams (approximate)



Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
(Type Number)-7* (Note 4)	SOD523	3000/Tape & Reel

^{*}Add "-7" to the appropriate type number in Electrical Characteristics Table, example: 6.2V Zener = BZT585B6V2T-7.

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xx = Product Type Marking Code (See Electrical Characteristics Table)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Charac	teristic	Symbol	Value	Unit
Forward Voltage	@ I _F = 10mA @ I _F = 100mA	V _F	0.9 1.1	V
Continuous Forward Current		l _F	200	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	350	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ heta JA}$	357	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-65 to +150	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

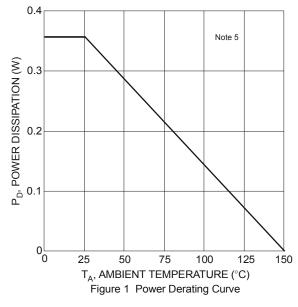
Type	Marking	Zener Voltage Range (Note 6)			Maximum Zener Impedance (Note 7)			Temperature Coefficient	Total Capacitance	Rev Cur	mum erse rent te 6)	
Number	Codes		Vz @ Izt		I _{ZT}	Z _{ZT} @	Z _{ZK} @	I _{ZK}	TC @ I _{ZT}	$C_T @ f = 1MHz,$ $V_R = 0V$	I _R	@ V _R
		Nom (V)	Min (V)	Max (V)	mA	2	Ω	mA	Typical (mV/°C)	Max (pF)	μΑ	٧
BZT585B2V4T	3C	2.4	2.35	2.45	5	100	400	1	-1.3	450	50	1
BZT585B2V7T	3E	2.7	2.65	2.75	5	100	450	1	-1.4	440	20	1
BZT585B3V3T	3H	3.3	3.23	3.37	5	95	500	1	-1.8	410	5	1
BZT585B3V6T	3J	3.6	3.53	3.67	5	90	500	1	-1.9	390	5	1
BZT585B3V9T	3K	3.9	3.82	3.98	5	90	500	1	-1.9	370	3	1
BZT585B4V3T	3L	4.3	4.21	4.39	5	90	600	1	-1.7	350	3	1
BZT585B4V7T	3M	4.7	4.61	4.79	5	80	500	1	-1.2	325	3	2
BZT585B5V1T	3N	5.1	5.00	5.20	5	60	480	1	-0.5	300	2	2
BZT585B5V6T	3P	5.6	5.49	5.71	5	40	400	1	1.0	275	1	2
BZT585B6V2T	3S	6.2	6.08	6.32	5	10	150	1	2.2	250	3	4
BZT585B6V8T	3T	6.8	6.66	6.94	5	15	80	1	3.0	215	2	4
BZT585B7V5T	3U	7.5	7.35	7.65	5	10	80	1	3.8	170	1	5
BZT585B8V2T	3V	8.2	8.04	8.36	5	10	80	1	4.7	150	0.7	5
BZT585B9V1T	3X	9.1	8.92	9.28	5	10	100	1	5.8	120	0.5	6
BZT585B10T	3Y	10	9.80	10.20	5	10	150	1	7.0	110	0.2	7
BZT585B11T	3Z	11	10.78	11.22	5	10	150	1	8.2	110	0.1	8
BZT585B12T	4A	12	11.76	12.24	5	10	150	1	9.5	105	0.1	8
BZT585B13T	4B	13	12.74	13.26	5	10	170	1	10.7	105	0.1	8
BZT585B15T	4D	15	14.70	15.30	5	15	200	1	13.2	100	0.05	10.5
BZT585B16T	4E	16	15.68	16.32	5	40	200	1	14.4	90	0.05	11.2
BZT585B18T	4F	18	17.64	18.36	5	45	225	1	16.9	80	0.05	12.6
BZT585B20T	4G	20	19.60	20.40	5	55	225	1	19.4	70	0.05	14.0
BZT585B22T	4H	22	21.56	22.44	5	55	250	1	21.9	60	0.05	15.4
BZT585B24T	4J	24	23.52	24.48	5	70	250	1	24.4	55	0.05	16.8
BZT585B27T	4K	27	26.46	27.54	2	80	300	0.5	25.4	50	0.05	18.9
BZT585B30T	4M	30	29.40	30.60	2	80	300	0.5	31.1	50	0.05	21.0
BZT585B33T	4N	33	32.34	33.66	2	80	325	0.5	36.7	45	0.05	23.1
BZT585B36T	4P	36	35.28	36.72	2	90	350	0.5	42.4	45	0.05	25.2
BZT585B39T	4R	39	38.22	39.78	2	130	350	0.5	48.1	45	0.05	27.3
BZT585B43T	4S	43	42.14	43.86	2	150	375	0.5	55.7	40	0.05	30.1

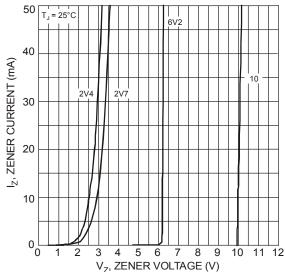
Notes: 6. Short duration pulse test used to minimize self-heating effect.

7. f = 1kHz.

^{5.} Device mounted on FR-4 PCB with minimum recommended pad layout, as shown in Diodes Incorporated's Suggested Pad Layout document, which can be found on our website at http://www.diodes.com.







1000 I_F, INSTANTANEOUS FORWARD CURRENT(mA) = 150°C 100 10 T_A = 85°C T_A = 25°C = -55°C 0.1 _____ 400 800 1000 1200 1400 600 V_F, INSTANTANEOUS FORWARD VOLTAGE(mV) Figure 2 Typical Forward Characteristics

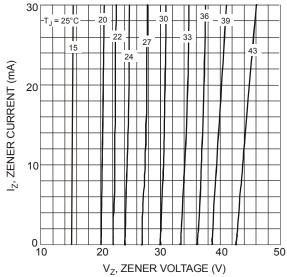
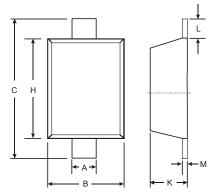


Figure 4 Typical Zener Breakdown Characteristics

Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Figure 3 Typical Zener Breakdown Characteristics



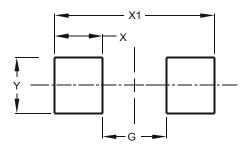
SOD523					
Dim	Min	Max			
Α	0.25	0.35			
В	0.70	0.90			
С	1.50	1.70			
Н	1.10	1.30			
K 0.55 0.65					
L 0.10 0.30					
М	0.10	0.12			
All Dimensions in mm					

CODESS



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
G	0.80
Х	0.60
X1	2.00
Y	0.70

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